

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSⅢ)

# TK40X10J1

Switching Regulator, DC-DC Converter Applications  
Motor Drive Applications

- Small gate charge :  $Q_g = 59 \text{ nC (typ.)}$
- Low drain-source ON-resistance:  $R_{DS(ON)} = 15 \text{ m}\Omega(\text{typ.})$
- High forward transfer admittance:  $|Y_{fs}| = 60 \text{ S (typ.)}$
- Low leakage current:  $I_{DSS} = 10 \text{ }\mu\text{A (max)} (V_{DS} = 100 \text{ V})$
- Enhancement mode:  $V_{th} = 3.0 \text{ to } 4.0 \text{ V} (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	100	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	100	V
Gate-source voltage		$V_{GSS}$	$\pm 20$	V
Drain current	DC (Note 1)	$I_D$	40	A
	Pulse (Note 1)	$I_{DP}$	160	
Drain power dissipation ( $T_c = 25^\circ\text{C}$ )		$P_D$	125	W
Single pulse avalanche energy (Note 2)		$E_{AS}$	99	mJ
Avalanche current		$I_{AR}$	40	A
Repetitive avalanche energy (Note 3)		$E_{AR}$	12.5	mJ
Channel temperature (Note 4)		$T_{ch}$	175	$^\circ\text{C}$
Storage temperature range (Note 4)		$T_{stg}$	-55 to 175	$^\circ\text{C}$

Note : Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	1.2	$^\circ\text{C/W}$

Note 1: Ensure that the channel temperature does not exceed  $175^\circ\text{C}$ .

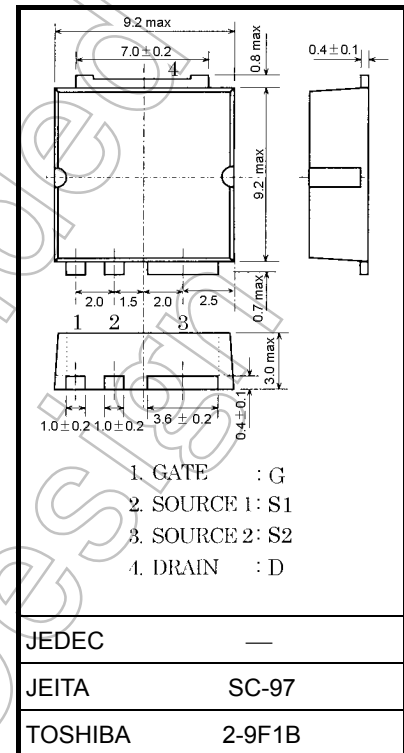
Note 2:  $V_{DD} = 25 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 100 \text{ }\mu\text{H}$ ,  $I_{AR} = 40 \text{ A}$ ,  $R_G = 1 \text{ }\Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

Note 4: The definitions of the absolute maximum channel temperature and storage temperatures are based on AEC-Q101.

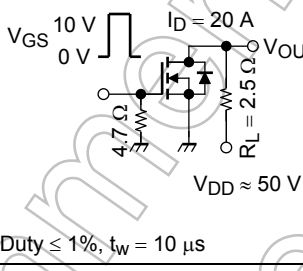
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.74 g (typ.)

## Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current		$I_{DSS}$	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	10	$\mu\text{A}$
Drain-source breakdown voltage	$V_{(BR) DSS}$		$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	100	—	—	V
	$V_{(BR) DSX}$		$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	55	—	—	V
Gate threshold voltage		$V_{th}$	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	3.0	—	4.0	V
Drain-source ON-resistance		$R_{DS(ON)}$	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	—	15	20	$\text{m}\Omega$
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10 \text{ V}, I_D = 20 \text{ A}$	30	60	—	S
Input capacitance		$C_{iss}$	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	3300	—	pF
Reverse transfer capacitance		$C_{rss}$		—	180	—	
Output capacitance		$C_{oss}$		—	580	—	
Switching time	Rise time	$t_r$		—	7	—	ns
	Turn-on time	$t_{on}$		—	25	—	
	Fall time	$t_f$		—	11	—	
	Turn-off time	$t_{off}$		—	66	—	
Total gate charge (gate-source plus gate-drain)		$Q_g$	$V_{DD} \approx 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 40 \text{ A}$	—	59	—	nC
Gate-source charge		$Q_{gs1}$		—	16	—	
Gate-switch charge		$Q_{gw}$		—	25	—	
Gate-drain ("miller") charge		$Q_{gd}$		—	19	—	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

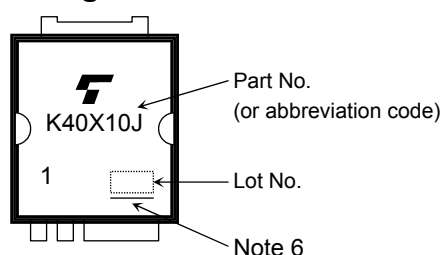
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1, Note 5)	$I_{DR1}$	—	—	—	40	A
Pulse drain reverse current (Note 1, Note 5)	$I_{DRP1}$	—	—	—	160	A
Continuous drain reverse current (Note 1, Note 5)	$I_{DR2}$	—	—	—	1	A
Pulse drain reverse current (Note 1, Note 5)	$I_{DRP2}$	—	—	—	4	A
Forward voltage (diode)	$V_{DS2F}$	$I_{DR1} = 40 \text{ A}, V_{GS} = 0 \text{ V}$	—	—	-1.2	V
Reverse recovery time	$t_{rr}$	$I_{DR} = 40 \text{ A}, V_{GS} = 0 \text{ V}, dI_{DR}/dt = 50 \text{ A}/\mu\text{s}$	—	77	—	ns
Reverse recovery charge	$Q_{rr}$		—	110	—	nC

Note 5:  $I_{DR1}, I_{DRP1}$ : Current flowing between the drain and S2 pins. Ensure that the S1 pin is left open.

$I_{DR2}, I_{DRP2}$ : Current flowing between the drain and S1 pins. Ensure that the S2 pin is left open.

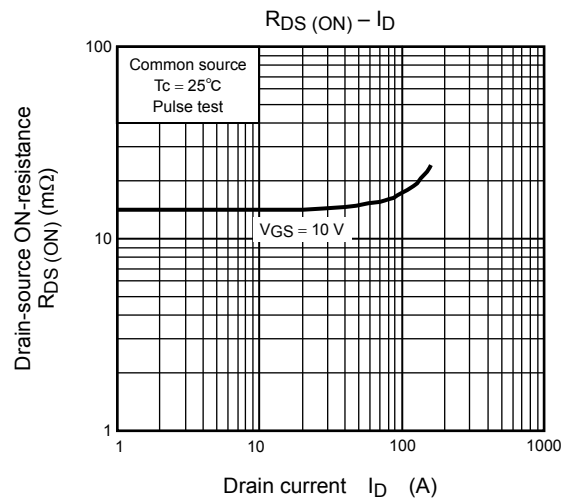
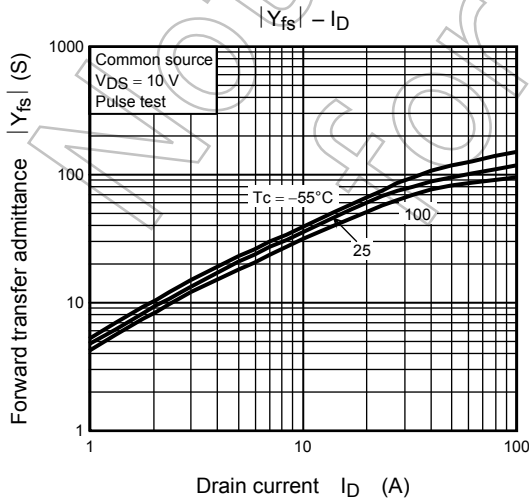
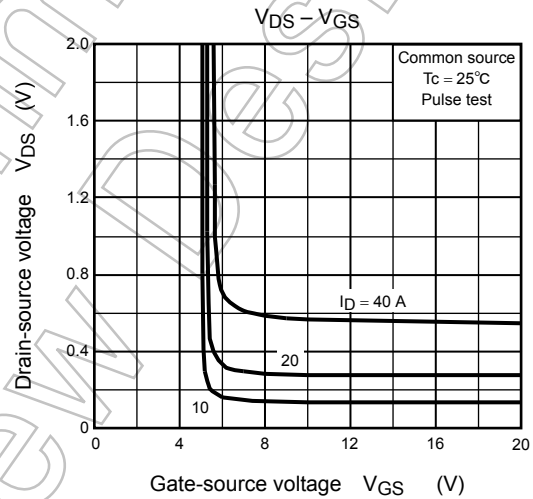
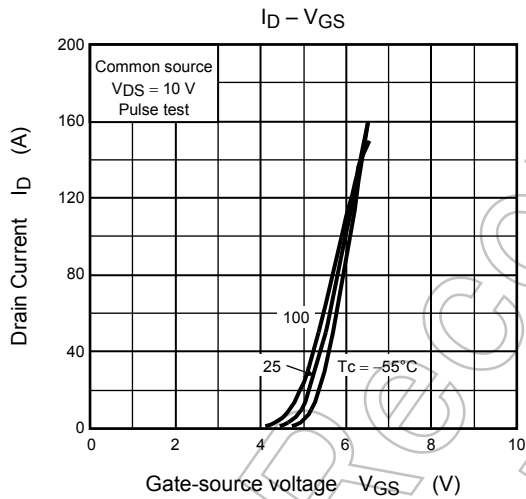
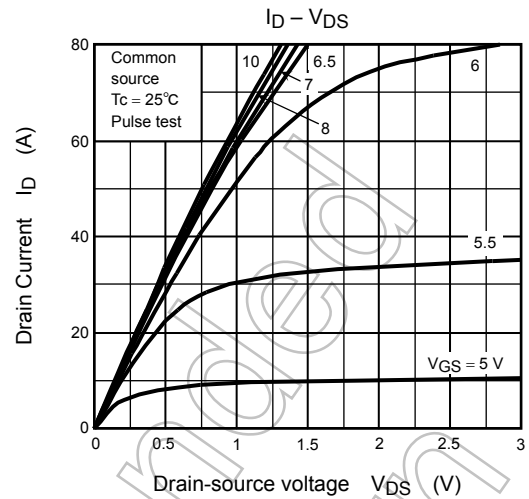
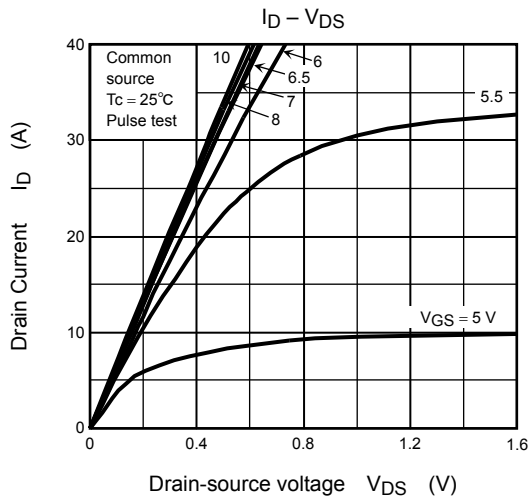
The S1 and S2 pins should be grounded together, unless otherwise noted.

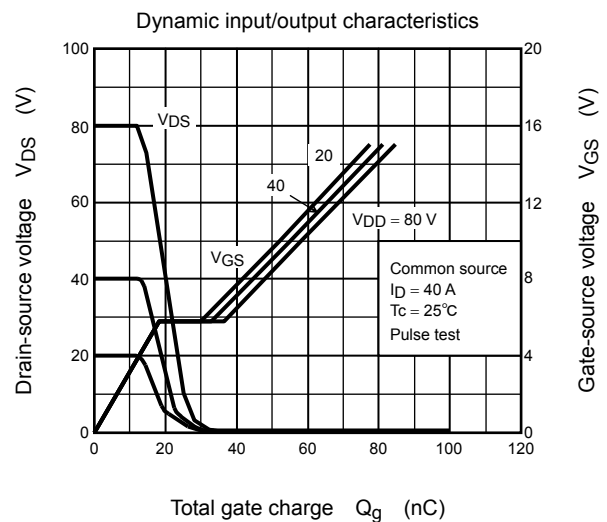
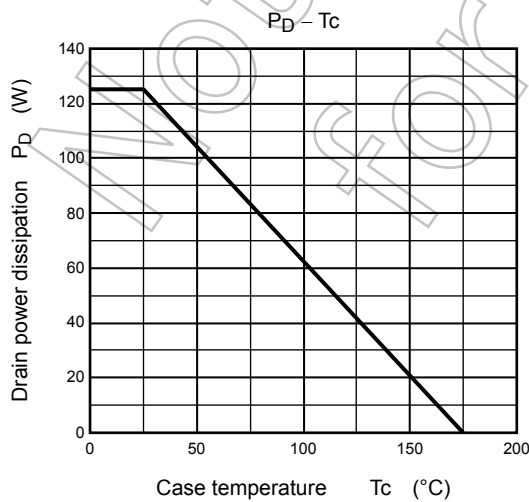
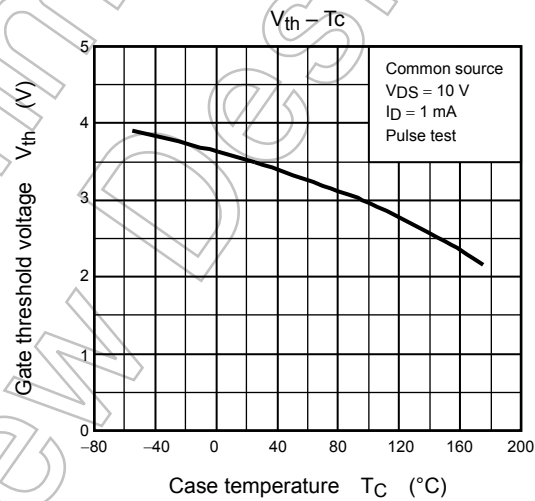
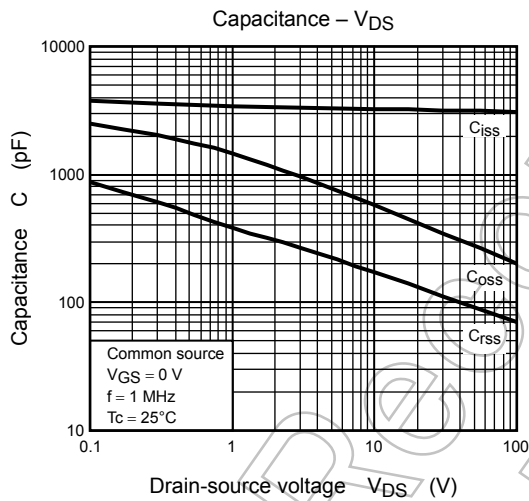
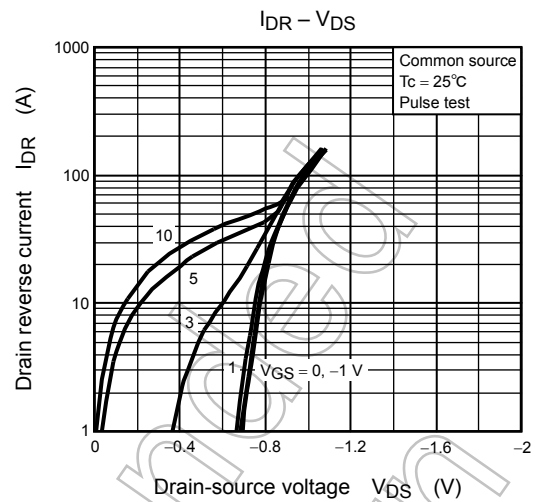
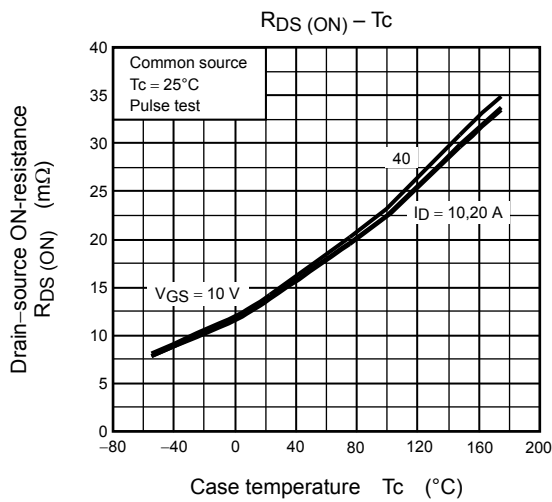
## Marking

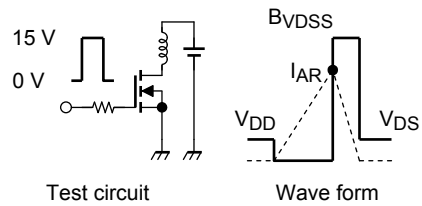
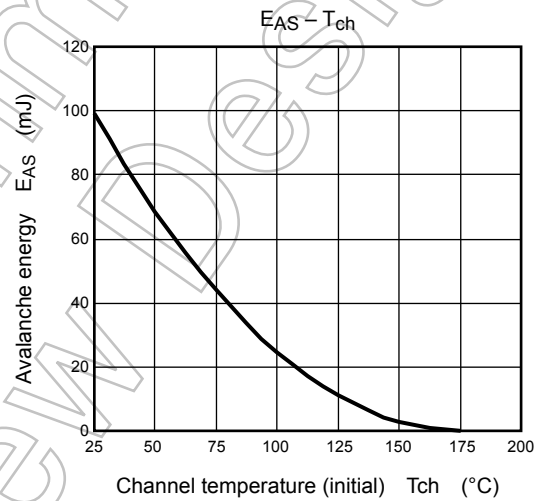
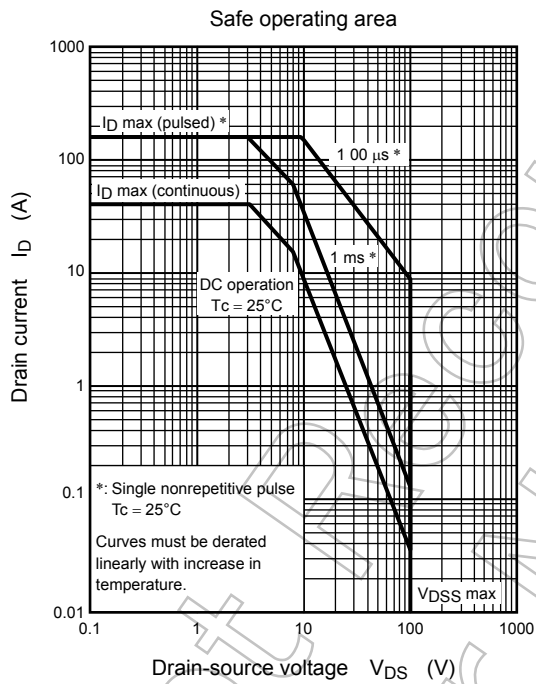
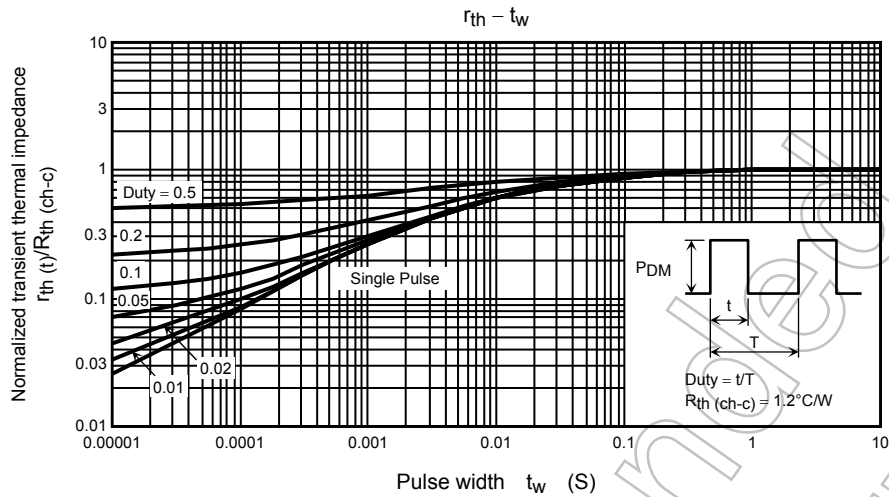


Note 6: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.







$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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